



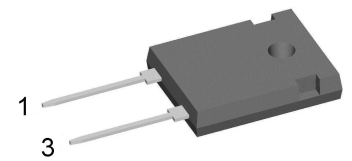
FRED

| | | |
|-----------|---|-------|
| V_{RRM} | = | 600 V |
| I_{FAV} | = | 25 A |
| t_{rr} | = | 35 ns |

Fast Recovery Epitaxial Diode Single Diode

Part number

DFE25I600HA



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

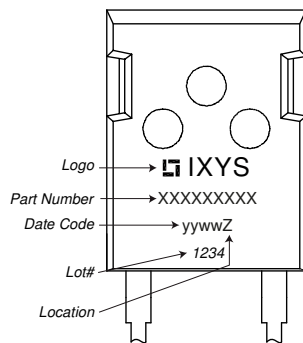
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| Fast Diode | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| I_R | reverse current, drain current | $V_R = 600 V$ | $T_{VJ} = 25^{\circ}C$ | | 100 | μA | |
| | | $V_R = 480 V$ | $T_{VJ} = 125^{\circ}C$ | | 6 | mA | |
| V_F | forward voltage drop | $I_F = 25 A$ | $T_{VJ} = 25^{\circ}C$ | | 1.50 | V | |
| | | $I_F = 50 A$ | | | 1.77 | V | |
| | | $I_F = 25 A$ | $T_{VJ} = 150^{\circ}C$ | | 1.35 | V | |
| | | $I_F = 50 A$ | | | 1.72 | V | |
| I_{FAV} | average forward current | $T_C = 100^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 150^{\circ}C$ | | 25 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 150^{\circ}C$ | | 1.10 | V | |
| r_F | slope resistance | | | | 10 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 1.2 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.25 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 105 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 240 | A | |
| C_J | junction capacitance | $V_R = 400 V$ $f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 20 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 30 A; V_R = 300 V$ $-di_F/dt = 200 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 9 | A | |
| | | | $T_{VJ} = 100^{\circ}C$ | | 14 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 25^{\circ}C$ | | 50 | ns | |
| | | | $T_{VJ} = 100^{\circ}C$ | | 120 | ns | |

| Package TO-247 | | | Ratings | | | |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 50 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 150 | °C |
| T_{op} | operation temperature | | -55 | | 125 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_D | mounting torque | | 0.8 | | 1.2 | Nm |
| F_C | mounting force with clip | | 20 | | 120 | N |

Product Marking

Part description

D = Diode
 F = FRED
 E = fast, low VF
 25 = Current Rating [A]
 I = Single Diode
 600 = Reverse Voltage [V]
 HA = TO-247AD (2)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DFE25I600HA | DFE25I600HA | Tube | 30 | 521189 |

| Similar Part | Package | Voltage class |
|--------------|----------------------|---------------|
| DSEI25-06A | TO-220AC (2) | 600 |
| DSEI25-06AS | TO-263AB (D2Pak) (2) | 600 |

Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 150^{\circ}\text{C}$

Fast Diode

| | | | |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage | 1.1 | V |
| $R_{0\ max}$ | slope resistance * | 7.5 | mΩ |



Outlines TO-247



| Sym. | Inches | | Millimeter | |
|------|-----------|-------|------------|-------|
| | min. | max. | min. | max. |
| A | 0.185 | 0.209 | 4.70 | 5.30 |
| A1 | 0.087 | 0.102 | 2.21 | 2.59 |
| A2 | 0.059 | 0.098 | 1.50 | 2.49 |
| D | 0.819 | 0.845 | 20.79 | 21.45 |
| E | 0.610 | 0.640 | 15.48 | 16.24 |
| E2 | 0.170 | 0.216 | 4.31 | 5.48 |
| e | 0.430 BSC | | 10.92 BSC | |
| L | 0.780 | 0.800 | 19.80 | 20.30 |
| L1 | - | 0.177 | - | 4.49 |
| Ø P | 0.140 | 0.144 | 3.55 | 3.65 |
| Q | 0.212 | 0.244 | 5.38 | 6.19 |
| S | 0.242 BSC | | 6.14 BSC | |
| b | 0.039 | 0.055 | 0.99 | 1.40 |
| b2 | 0.065 | 0.094 | 1.65 | 2.39 |
| b4 | 0.102 | 0.135 | 2.59 | 3.43 |
| c | 0.015 | 0.035 | 0.38 | 0.89 |
| D1 | 0.515 | - | 13.07 | - |
| D2 | 0.020 | 0.053 | 0.51 | 1.35 |
| E1 | 0.530 | - | 13.45 | - |
| Ø P1 | - | 0.29 | - | 7.39 |



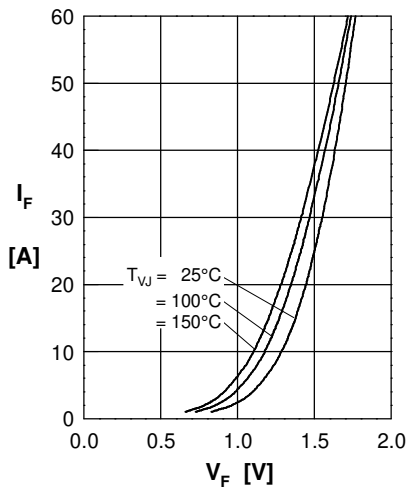
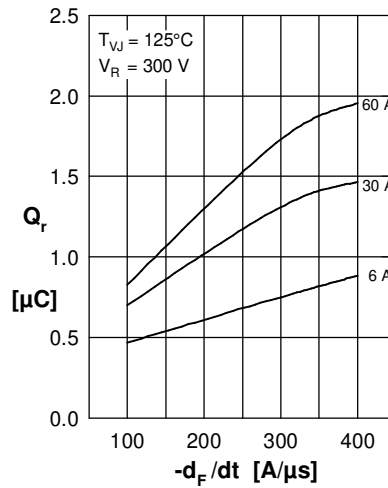
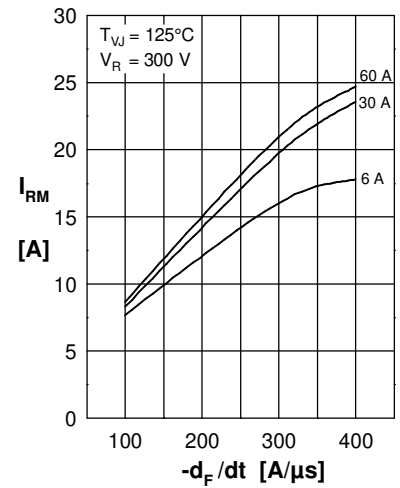
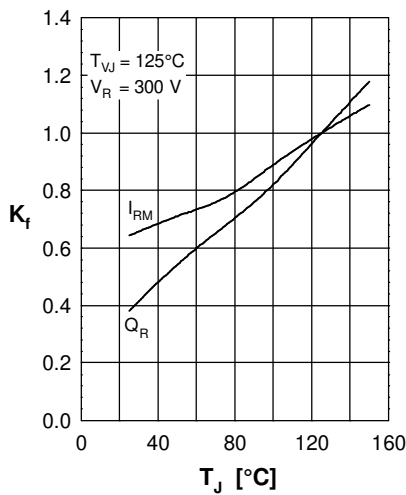
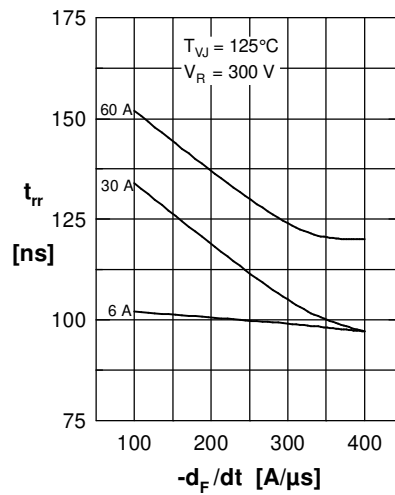
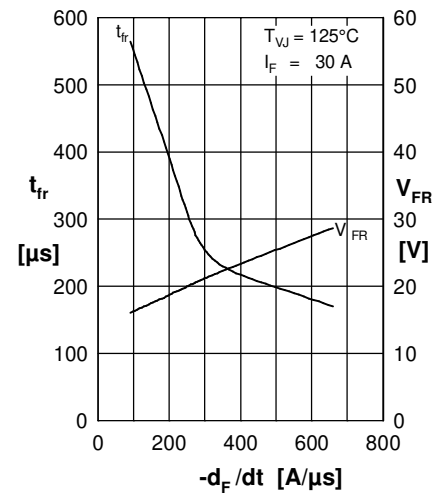
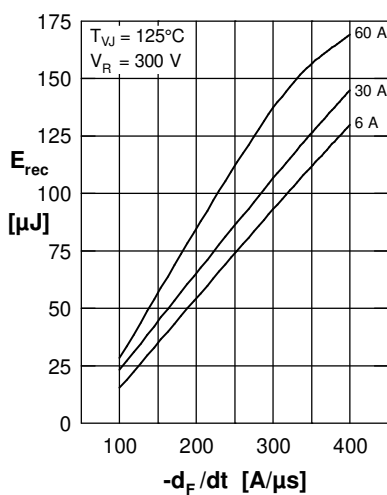
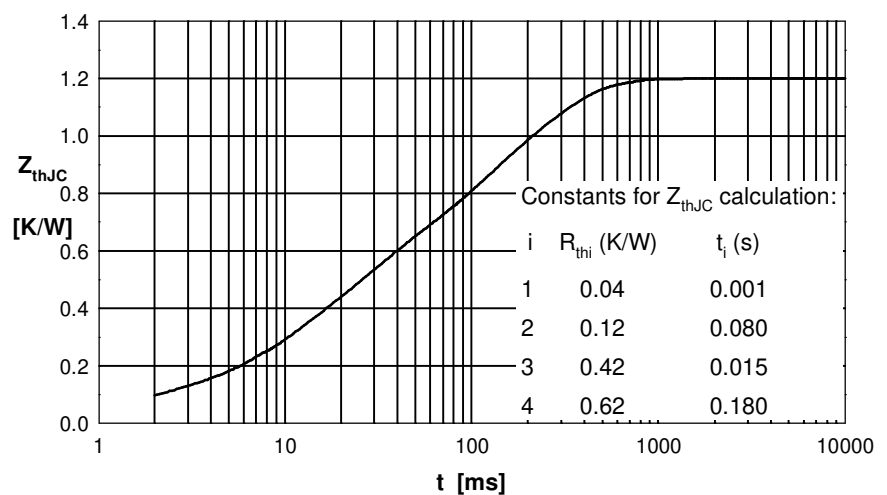
Fast Diode

 Fig. 1 Forward current I_F versus max. forward voltage drop V_F

 Fig. 2 Typ. reverse recov. charge Q_r versus $-di_F/dt$

 Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

 Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

 Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

 Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt

 Fig. 7 Recovery energy E_{rec} versus $-di_F/dt$


Fig. 8 Transient thermal impedance junction to case